



**SOLAR ENERGY
TECHNOLOGIES OFFICE**
U.S. Department Of Energy

PORTFOLIO REVIEW

2018



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2018 SETO Portfolio Review

Silicon-Based Tandem Photovoltaic Cells

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Arizona State University

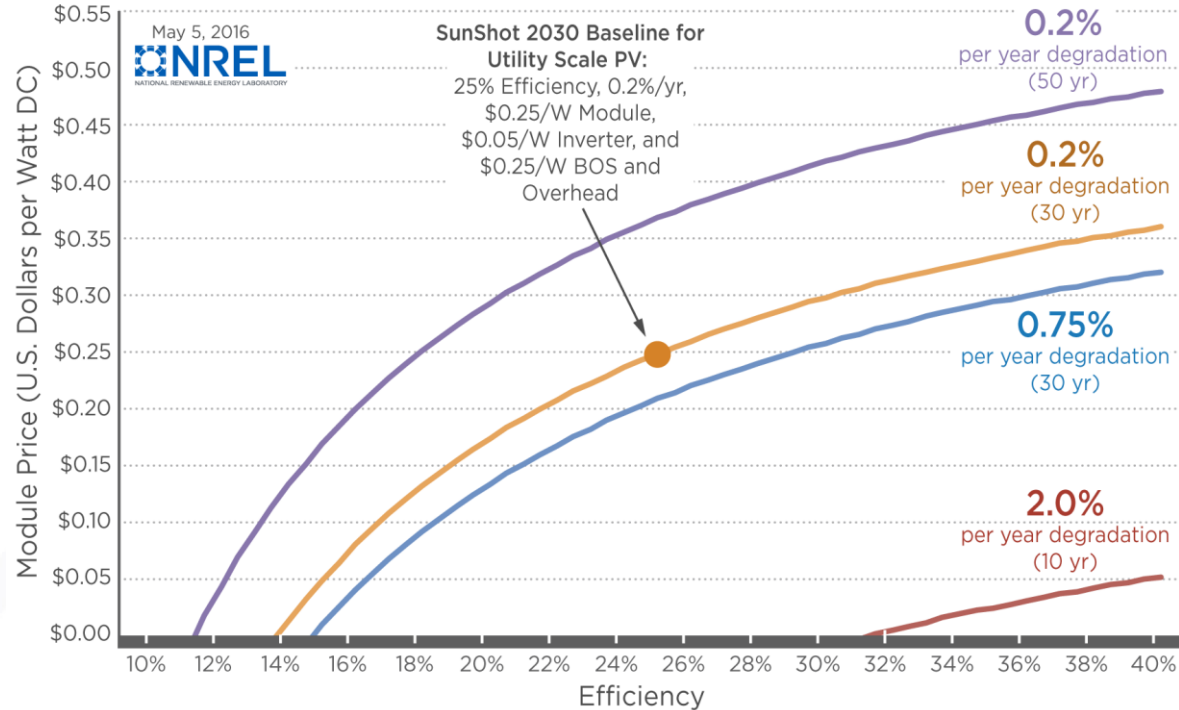
energy.gov/solar-office

SETO Mantra: Efficiency, Reliability, Cost

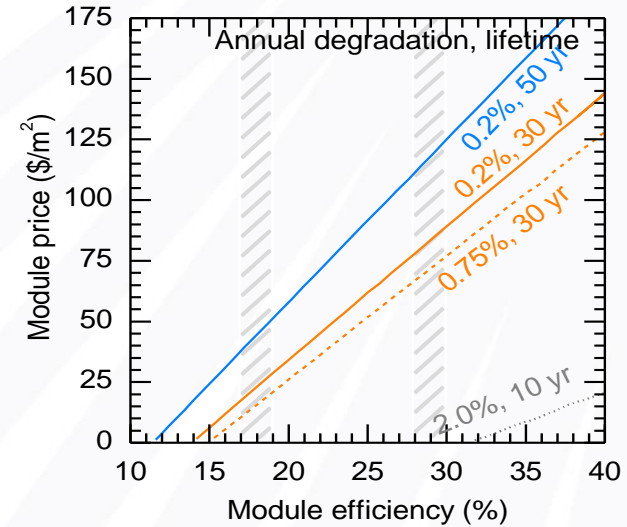
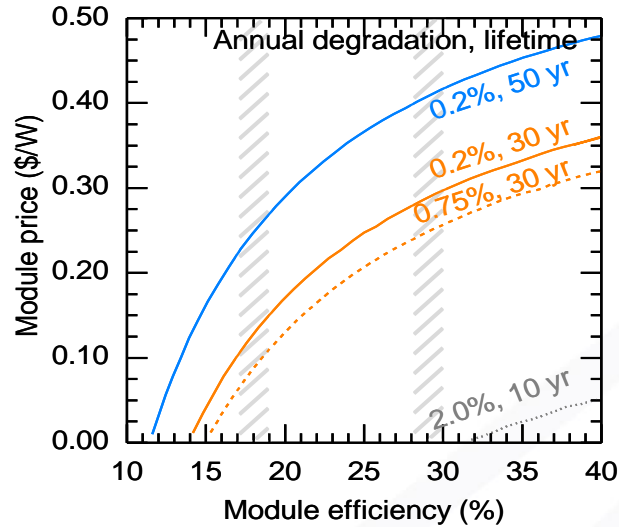


Metric Sets to Achieve a 3 Cents per kWh Goal

Iso-LCOE curves of 3 cents per kWh without federal or state incentives and with 1,480 kWh/kW first-year performance. 7.0% nominal discount rate.

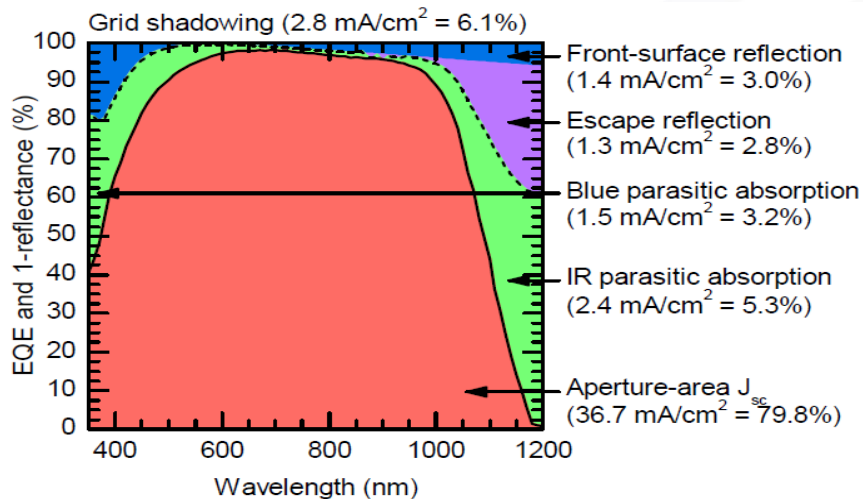
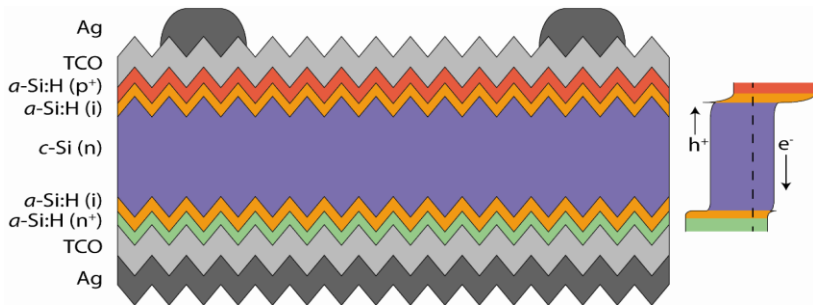


SETO Mantra: Efficiency, Reliability, Cost



➤ Doubling efficiency more than doubles module selling price

What Will the Silicon Bottom Cell Look Like?

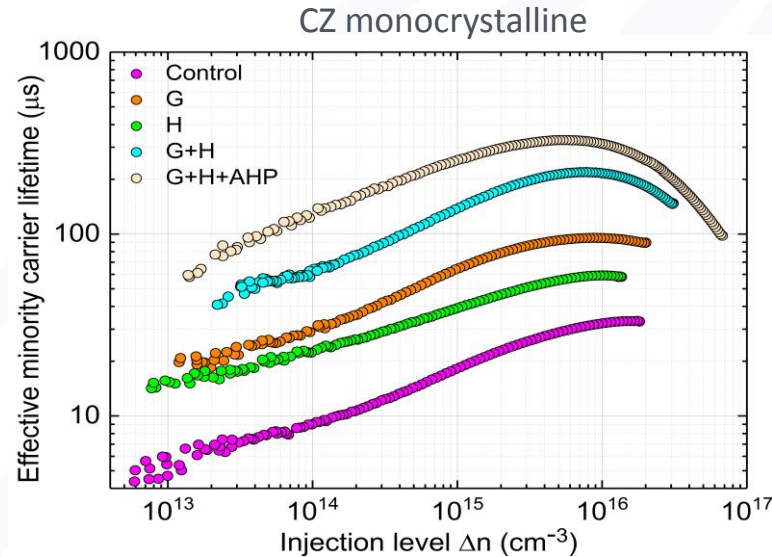


- Silicon heterojunction (SHJ) cells have highest V_{oc} s
- Blue parasitic absorption is non-issue in tandems
- Front TCO is a natural recombination junction
- Expensive low-temperature silver paste not needed for two-terminal tandems
- Benefits from a high-lifetime (n-type wafer)
- TCOs and rear metallization can be pricey

Silicon Heterojunction Bottom Cell: Solar-Grade p -Type Wafers

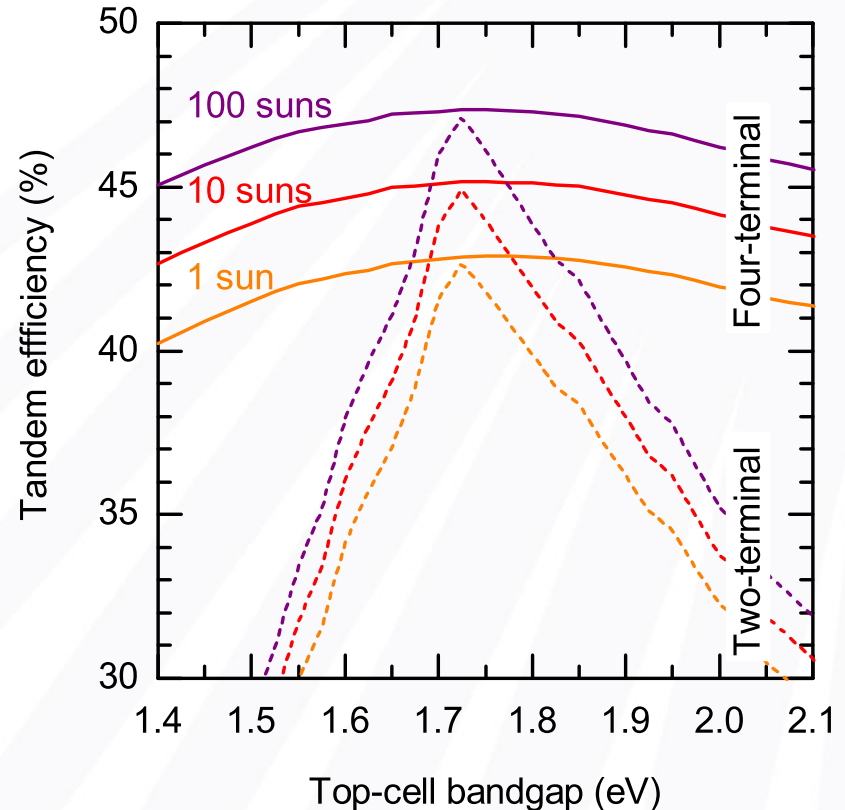


- Gettering (G), hydrogenation (H), and advanced hydrogenation (AHP) improves p -type SHJ lifetime from 30 μs to 300 μs
- Certified V_{oc} of 707 mV on p -type CZ, 702 mV on p -type multi



What Will the Top Cell Look Like?

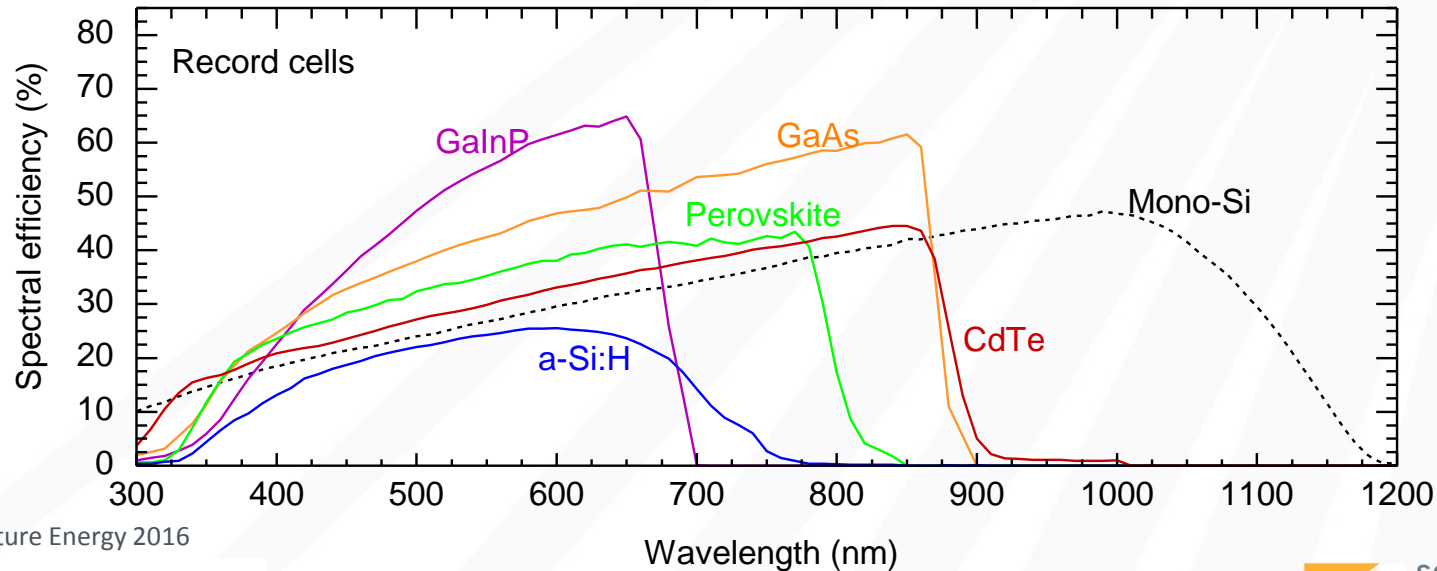
- Limiting-efficiency calculations including Auger recombination give 43%
- 1.72 eV top cell is best for two-terminal tandem; 1.6–1.9 eV for four-terminal
- But we don't make sub-cells that operate at their limiting efficiency!



Spectral Efficiency Shows the Way

$$\eta(\lambda) = \frac{J_{sc}(\lambda) \cdot V_{oc} \cdot FF}{I(\lambda)} \quad \text{with} \quad J_{sc}(\lambda) = q \frac{\lambda}{hc} EQE(\lambda) \cdot I(\lambda)$$

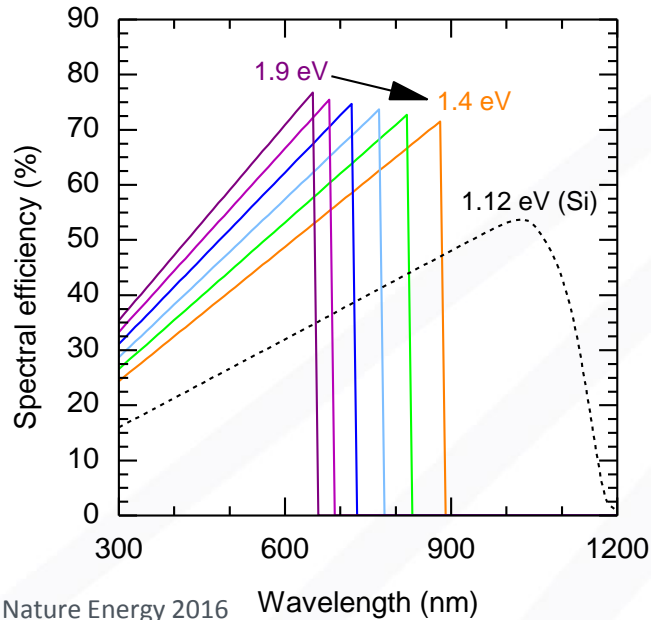
- Efficiency resolved by wavelength
- Allows direct evaluation of cell pairs—only bother considering a tandem if top cell is considerably better than silicon for $\lambda < 700$ nm



Yu *et al*, Nature Energy 2016

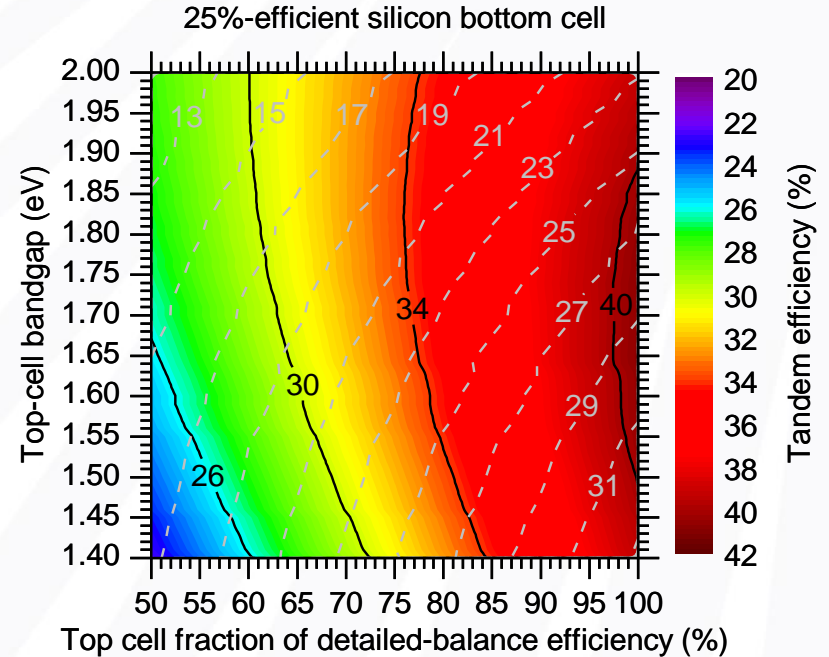
Spectral Efficiency Shows the Way

- Predicts the maximum possible tandem efficiency for any two sub-cells



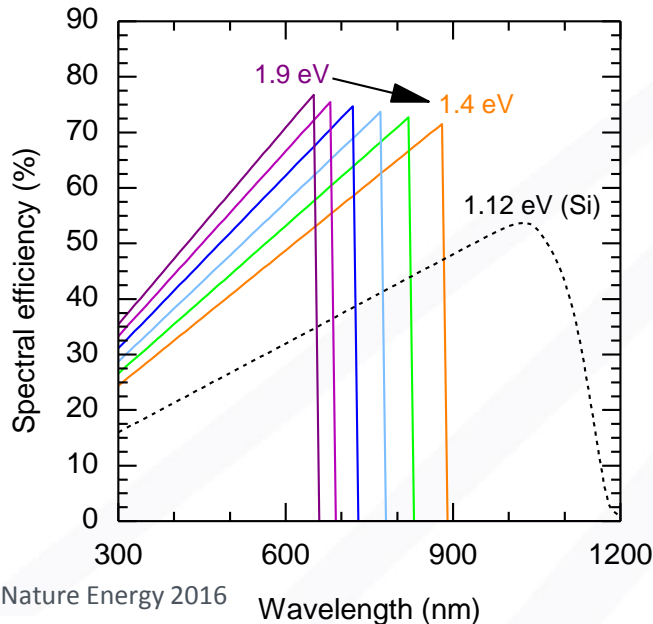
Yu et al, Nature Energy 2016

Wavelength (nm)



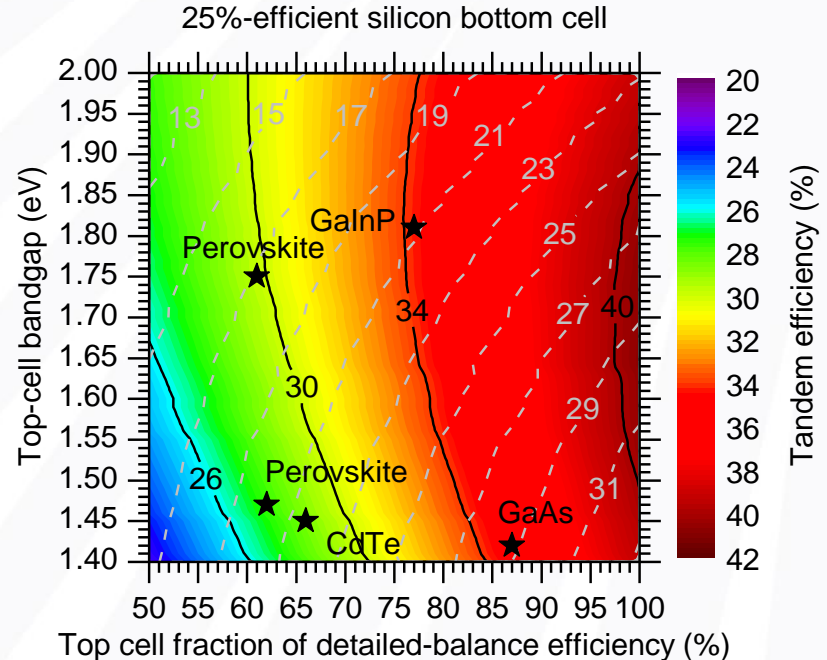
Spectral Efficiency Shows the Way

- Predicts the maximum possible tandem efficiency for any two sub-cells
- Of existing cells, GaAs gives highest tandem efficiency despite wrong bandgap!



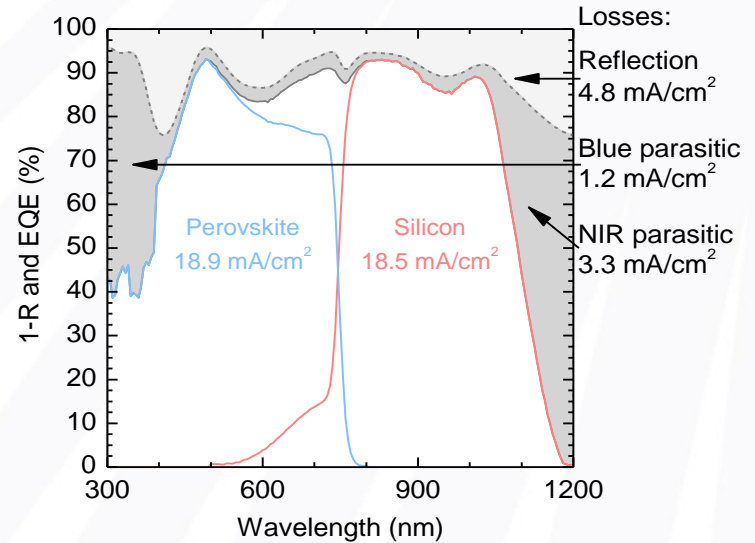
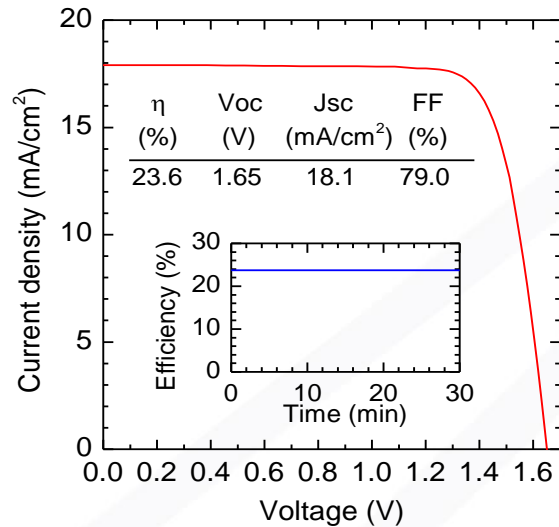
Yu et al, Nature Energy 2016

Wavelength (nm)



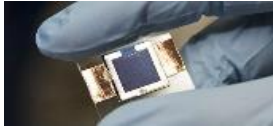
Perovskite Top Cells

- + Amazing lifetime and V_{oc} for polycrystalline material, potentially inexpensive
- Stability, scaling, depositing on textured surfaces

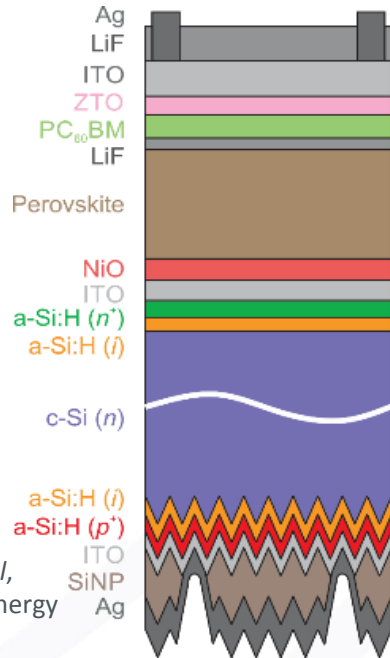


Bush *et al*, Nature Energy 2017

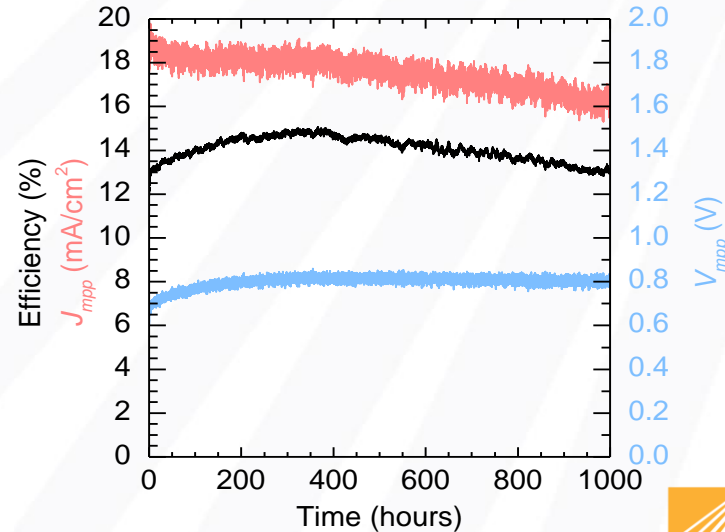
Perovskite Top Cells



- Thermally stable absorber:
 $\text{Cs}_{0.17}\text{FA}_{0.83}\text{Pb}(\text{Br}_{0.17}\text{I}_{0.83})_3$ (CsFA) perovskite
- Thermally evaporated PCBM (electron contact)
- ALD-deposited SnO_2 /ZTO buffer layer prevents sputter damage

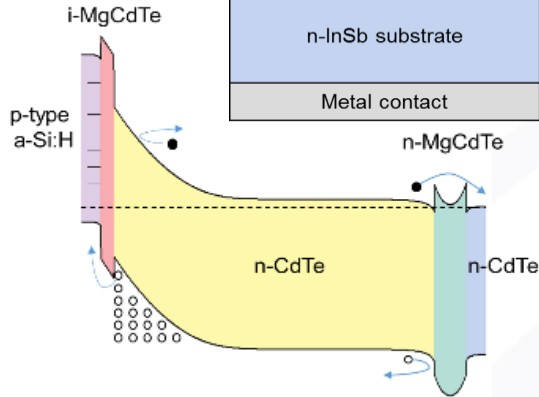


Bush *et al*,
Nature Energy
2017



CdMgTe and CdZnTe Top Cells

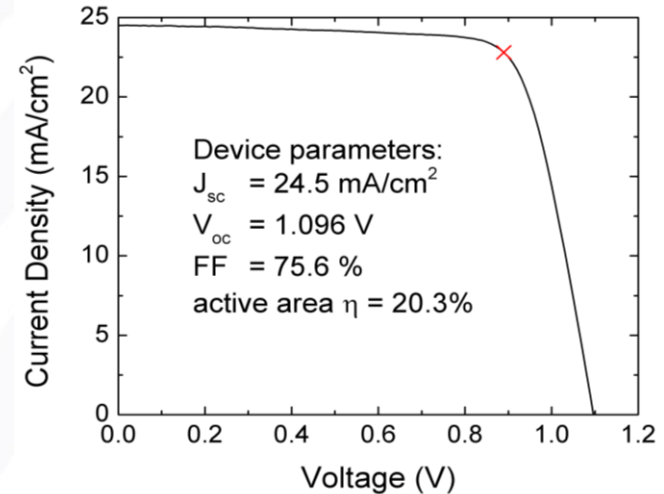
ITO	55 nm
p-type a-Si:H	8 nm
i-Mg _{0.4} Cd _{0.6} Te	15 nm
n-CdTe absorber $N_D = 10^{16} \text{ cm}^{-3}$	1 μm
n-Mg _{0.24} Cd _{0.76} Te BSB $N_D = 5 \times 10^{17} \text{ cm}^{-3}$	50 nm
n-CdTe buffer $N_D = 5 \times 10^{17} \text{ cm}^{-3}$	500 nm
n-InSb buffer $N_D = 5 \times 10^{17} \text{ cm}^{-3}$	500 nm
n-InSb substrate	
Metal contact	



Zhao *et al*, Nature Energy 2016; Becker *et al*, IEEE JPV 2017

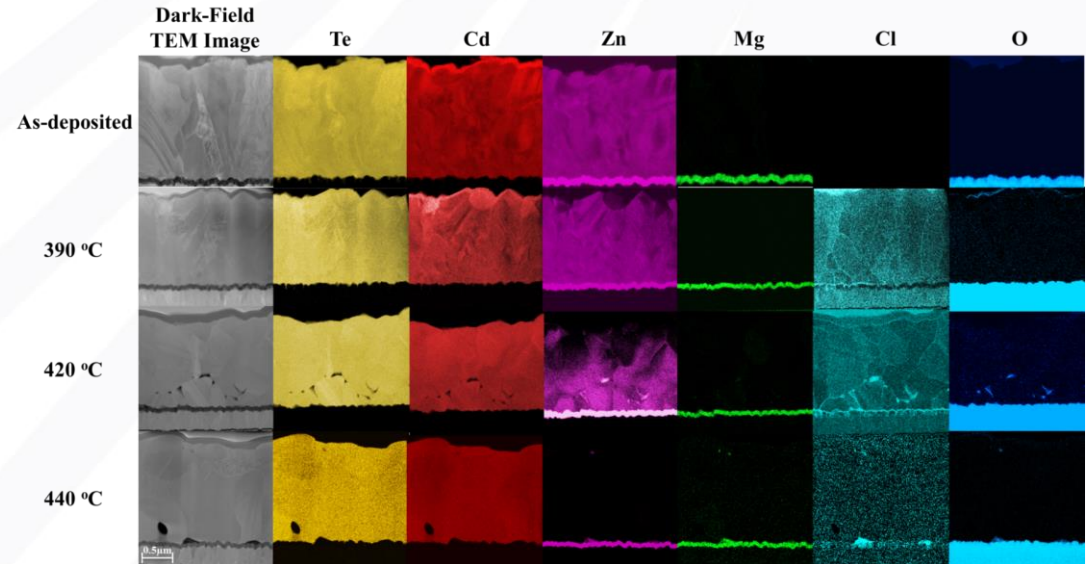
+ CdTe cells at 22%, Mg or Zn to get to 1.7 eV, GW-scale manufacturing in place

- Ternary alloys are complicated, V_{oc} of II-VI cells low due in part to back contact



CdMgTe and CdZnTe Top Cells

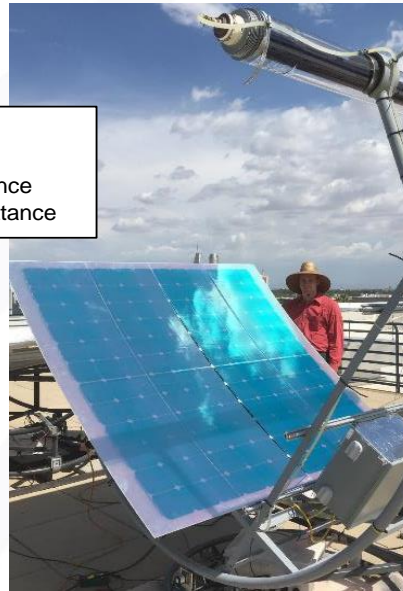
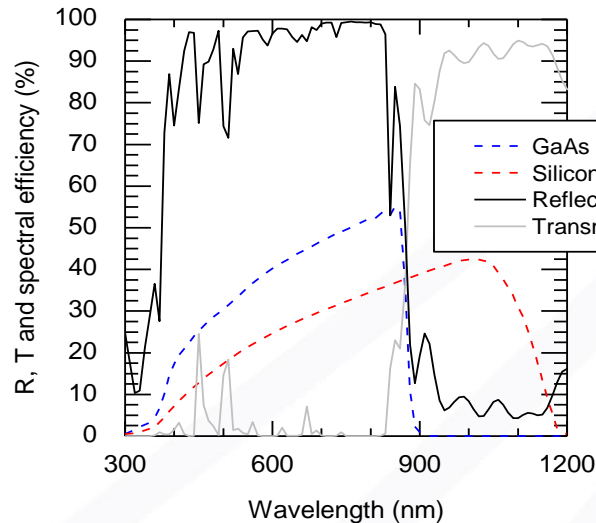
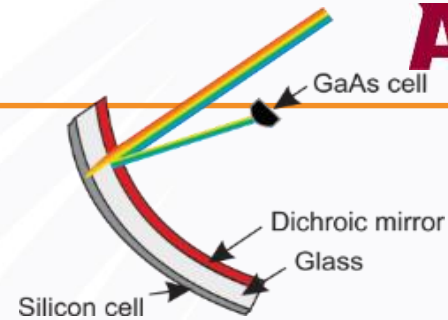
- Best 1.7 eV monocrystalline CdMgTe cell at 15.2%; reached $V_{oc} = 1.18$ V and FF = 82% separately
- Polycrystalline CdMgTe and CdZnTe lose Mg and Zn upon CdCl₂ treatment
- Best 1.65 eV polycrystalline CdMgTe cell at 10.2%; lifetime of 7 ns with double heterostructure



Swanson *et al*, submitted; Becker *et al*, IEEE JPV 2018

III-V Top Cells

- + Monocrystalline cells are very efficient, stable
- Cost, integration with silicon



Yu et al, in preparation

Acknowledgements



ANU (Macdonald)

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Stanford (McGehee)

UNC (Huang)

UNSW (Hallam)

UA (Angel)

UIUC (Lee)



- *Long-lifetime, cheap, stable polycrystalline absorbers*
 - Perovskite: Degradation mechanisms? Conformal deposition on 156 mm textured wafers?
 - II-VI: Maintain alloy stoichiometry during Cl treatment? Surface passivation?
 - III-V: Any plausible way to get these to < \$100/m²? Passivation of grain boundaries in polycrystalline III-V materials?
 - Other absorbers that we're not yet exploring?

- *Heterojunction contacts with high or low work function*
 - Measurement of implied voltage, comparison to extracted voltage?
 - New, transparent high- and low-work-function materials?
 - Deposition methods that don't damage absorbers?

- *Integration with silicon*
 - Process compatibility (temperature, chemistry)?
 - Two, three, or four terminals? Realistic energy yield calculations?
 - Metallization when combining a thin-film solar cell with a wafer-based solar cell?

